

GaN Power Amplifier DM-HPMB-25-101

Electrical Specifications (+25°C)

PARAMETER	UNITS
Frequency	6 to 18 GHz
Small Signal Gain	50 dB min
Gain Var. Over Temp	-0.05 dB/°C typical
Psat @ 5dBm Input	6-12 GHz > 42; 12-18 GHz > 40 dBm min
Psat @ 5dBm Input	15 W typical
Noise Figure	8 dB max
DC Power	28 VDC, 4.5 A nom at Psat
PAE	15 % typical
VSWR (Input/Output)	2.0:1/2.0:1 nom
Harmonics	-12 dBc typical @ Psat
Spurious	-70 dBc typical
Input Power Handling	15 dBm max
Mismatch Handling	5.0:1 max
Operation	CW

Mechanical Specifications

PARAMETER	UNITS
Size (L x W x H)	2.5" x 2.75" x 0.45"
Connectors (In/Out)	SMA (f)/SMA (f)
Sealing	Hermetic
Finish	Grey Paint, Mounting surface Ni finish
Marking	Black per MIL-STD-130
Cooling	External heatsink
Outline	001-0013

Features

PARAMETER	UNITS
DC On/Off	1µs; TTL Logic-Low "0V": ON; High "5V": OFF
Over Temp Shutdown	at +80°C
Current Monitoring	Included

Environmental Specifications (by design)

PARAMETER	UNITS
Operating Temperature	-40 to +70°C
Storage Temperature	-54 to +85°C
Relative Humidity	IAW MIL-STD-810F, up to 95%
Altitude	up to 30,000 ft
Vibration	IAW MIL-STD-810F, Method 514.5, Table 514.5-I, Categories 12, 13, 14, 20
Shock	IAW MIL-STD-202G method 214, condition C
Salt Fog	5%, +35°C 96 hrs IAW MIL-STD- 810G method
Fungus	IAW MIL-STD-810G method 508.6

Classification

ECCN: ITAR

Test Data

Gain, Psat, VSWR, DC Power at +25°C